Onsemi

Industrial Inductive Load Driver

NUD3160, SZNUD3160

This micro-integrated part provides a single component solution to switch inductive loads such as relays, solenoids, and small DC motors without the need of a free-wheeling diode. It accepts logic level inputs, thus allowing it to be driven by a large variety of devices including logic gates, inverters, and microcontrollers.

Features

- Provides Robust Interface between D.C. Relay Coils and Sensitive Logic
- Capable of Driving Relay Coils Rated up to 150 mA at 12 V, 24 V or 48 V
- Replaces 3 or 4 Discrete Components for Lower Cost
- Internal Zener Eliminates Need for Free–Wheeling Diode
- Meets Load Dump and other Automotive Specs
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and **PPAP** Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Automotive and Industrial Environment
- Drives Window, Latch, Door, and Antenna Relays

Benefits

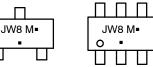
- Reduced PCB Space
- Standardized Driver for Wide Range of Relays
- Simplifies Circuit Design and PCB Layout
- Compliance with Automotive Specifications



SOT-23 **CASE 318** STYLE 21

SC-74 **CASE 318F** STYLE 7





= Specific Device Code JW8 Μ

- = Date Code = Pb-Free Package
- (Note: Microdot may be in either location)

- М = Date Code
- = Pb-Free Package
- (Note: Microdot may be in either location)

ORDERING INFORMATION

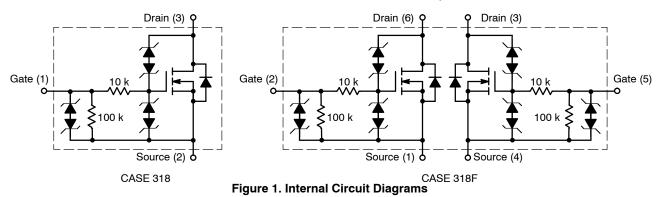
Device	Package	Shipping [†]
SZNUD3160LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
SZNUD3160DMT1G	SC–74 (Pb–Free)	3000 / Tape & Reel

DISCONTINUED (Note 1)

NU31D60LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
NUD3160DMT1G	SC-74 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

1. DISCONTINUED: These devices are not recommended for new design. Please contact your onsemi representative for information. The most current information on these devices may be available on www.onsemi.com.



MAXIMUM RATINGS (T_J = 25° C unless otherwise specified)

Symbol	Rating	Value	Unit
V _{DSS}	Drain-to-Source Voltage - Continuous (T _J = 125°C)	60	V
V _{GSS}	Gate-to-Source Voltage – Continuous (T _J = 125°C)	12	V
ID	Drain Current – Continuous ($T_J = 125^{\circ}C$) Minimum copper, double sided board, $T_A = 80^{\circ}C$ SOT-23 SC74 Single device driven SC74 Both devices driven 1 in ² copper, double sided board, $T_A = 25^{\circ}C$ SOT-23 SC74 Single device driven SC74 Both devices driven	158 157 132 ea 272 263 230 ea	mA
EZ	Single Pulse Drain-to-Source Avalanche Energy (For Relay's Coils/Inductive Loads of 80 Ω or Higher) (T _J Initial = 85°C)	200	mJ
P _{PK}	Peak Power Dissipation, Drain-to-Source (Notes 2 and 3) $(T_J \text{ Initial} = 85^{\circ}\text{C})$	20	W
E _{LD1}	Load Dump Pulse, Drain-to-Source (Note 4) $R_{SOURCE} = 0.5 \Omega$, T = 300 ms) (For Relay's Coils/Inductive Loads of 80 Ω or Higher) (T _J Initial = 85°C)	60	V
E _{LD2}	Inductive Switching Transient 1, Drain-to-Source (Waveform: $R_{SOURCE} = 10 \Omega$, T = 2.0 ms) (For Relay's Coils/Inductive Loads of 80 Ω or Higher) (T _J Initial = 85°C)	100	V
E _{LD3}	Inductive Switching Transient 2, Drain-to-Source (Waveform: $R_{SOURCE} = 4.0 \Omega$, T = 50 µs) (For Relay's Coils/Inductive Loads of 80 Ω or Higher) (T _J Initial = 85°C)	300	V
Rev-Bat	Reverse Battery, 10 Minutes (Drain-to-Source) (For Relay's Coils/Inductive Loads of 80 Ω or more)	-14	V
Dual-Volt	Dual Voltage Jump Start, 10 Minutes (Drain-to-Source)	28	V
ESD	Human Body Model (HBM) According to EIA/JESD22/A114 Specification	2000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Symbol	Rating	Value	Unit
T _A	Operating Ambient Temperature	-40 to 125	°C
TJ	Maximum Junction Temperature	150	°C
T _{STG}	Storage Temperature Range	-65 to 150	°C
PD	Total Power Dissipation (Note 5)SOT-23Derating above 25°CSOT-23	225 1.8	mW mW/°C
PD	Total Power Dissipation (Note 5) SC-74 Derating above 25°C SC-74	380 3.0	mW mW/°C
$R_{ heta JA}$	Thermal Resistance, Junction-to-Ambient Minimum Copper SOT-23 SC-74 One Device Powered SC-74 Both Devices Equally Powered	556 556 398	°C/W
	300 mm ² Copper SOT-23 SC-74 One Device Powered SC-74 Both Devices Equally Powered	395 420 270	

2. Nonrepetitive current square pulse 1.0 ms duration.

For different square pulse durations, see Figure 12.
Nonrepetitive load dump pulse per Figure 3.
Mounted onto minimum pad board.

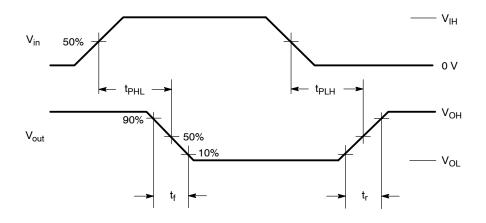
ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise specified)

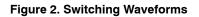
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Drain to Source Sustaining Voltage (I _D = 10 mA)	V _{BRDSS}	61	66	70	V
$ Drain to Source Leakage Current \\ (V_{DS} = 12 V, V_{GS} = 0 V) \\ (V_{DS} = 12 V, V_{GS} = 0 V, T_J = 125^{\circ}C) \\ (V_{DS} = 60 V, V_{GS} = 0 V) \\ (V_{DS} = 60 V, V_{GS} = 0 V, T_J = 125^{\circ}C) \\ \end{array} $	IDSS	- - -	- - - -	0.5 1.0 50 80	μΑ
Gate Body Leakage Current ($V_{GS} = 3.0 \text{ V}, V_{DS} = 0 \text{ V}$) ($V_{GS} = 3.0 \text{ V}, V_{DS} = 0 \text{ V}, T_J = 125^{\circ}\text{C}$) ($V_{GS} = 5.0 \text{ V}, V_{DS} = 0 \text{ V}$) ($V_{GS} = 5.0 \text{ V}, V_{DS} = 0 \text{ V}, T_J = 125^{\circ}\text{C}$)	I _{GSS}	- - -	- - -	60 80 90 110	μΑ
ON CHARACTERISTICS					
Gate Threshold Voltage $(V_{GS} = V_{DS}, I_D = 1.0 \text{ mA})$ $(V_{GS} = V_{DS}, I_D = 1.0 \text{ mA}, T_J = 125^{\circ}\text{C})$	V _{GS(th)}	1.3 1.3	1.8 _	2.0 2.0	V
Drain to Source On-Resistance ($I_D = 150 \text{ mA}, V_{GS} = 3.0 \text{ V}$) ($I_D = 150 \text{ mA}, V_{GS} = 3.0 \text{ V}, T_J = 125^{\circ}\text{C}$) ($I_D = 150 \text{ mA}, V_{GS} = 5.0 \text{ V}$) ($I_D = 150 \text{ mA}, V_{GS} = 5.0 \text{ V}, T_J = 125^{\circ}\text{C}$)	R _{DS(on)}	- - -	- - -	2.4 3.7 1.8 2.9	Ω
Output Continuous Current ($V_{DS} = 0.3 \text{ V}, V_{GS} = 5.0 \text{ V}$) ($V_{DS} = 0.3 \text{ V}, V_{GS} = 5.0 \text{ V}, T_J = 125^{\circ}\text{C}$)	I _{DS(on)}	150 100	200 _		mA
Forward Transconductance $(V_{DS} = 12 \text{ V}, I_D = 150 \text{ mA})$	9fs	-	400	-	mmho
DYNAMIC CHARACTERISTICS	-	-	-	-	
Input Capacitance (V _{DS} = 12 V, V _{GS} = 0 V, f = 10 kHz)	C _{iss}	_	30	-	pf
Output Capacitance (V _{DS} = 12 V, V _{GS} = 0 V, f = 10 kHz)	C _{oss}	-	14	-	pf
Transfer Capacitance (V _{DS} = 12 V, V _{GS} = 0 V, f = 10 kHz)	C _{rss}	_	6.0	-	pf
SWITCHING CHARACTERISTICS	_	_	_	_	
Propagation Delay Times: High to Low Propagation Delay; Figure 2, $(V_{DS} = 12 \text{ V}, V_{GS} = 3.0 \text{ V})$ Low to High Propagation Delay; Figure 2, $(V_{DS} = 12 \text{ V}, V_{GS} = 3.0 \text{ V})$	t _{PHL} t _{PLH}		918 798		ns
High to Low Propagation Delay; Figure 2, (V _{DS} = 12 V, V _{GS} = 5.0 V) Low to High Propagation Delay; Figure 2, (V _{DS} = 12 V, V _{GS} = 5.0 V)	t _{PHL} t _{PLH}	_	331 1160	-	
Transition Times: Fall Time; Figure 2, (V _{DS} = 12 V, V _{GS} = 3.0 V) Rise Time; Figure 2, (V _{DS} = 12 V, V _{GS} = 3.0 V)	t _f tr		2290 618		ns
Fall Time; Figure 2, (V $_{DS}$ = 12 V, V $_{GS}$ = 5.0 V) Rise Time; Figure 2, (V $_{DS}$ = 12 V, V $_{GS}$ = 5.0 V)	t _f t _r		622 600	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL WAVEFORMS

(T_J = 25°C unless otherwise specified)





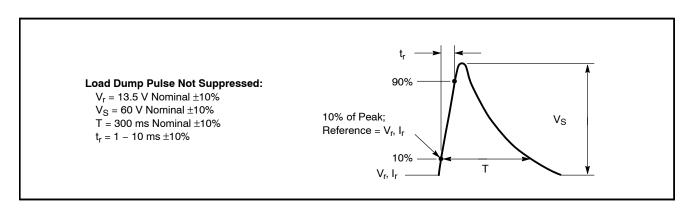
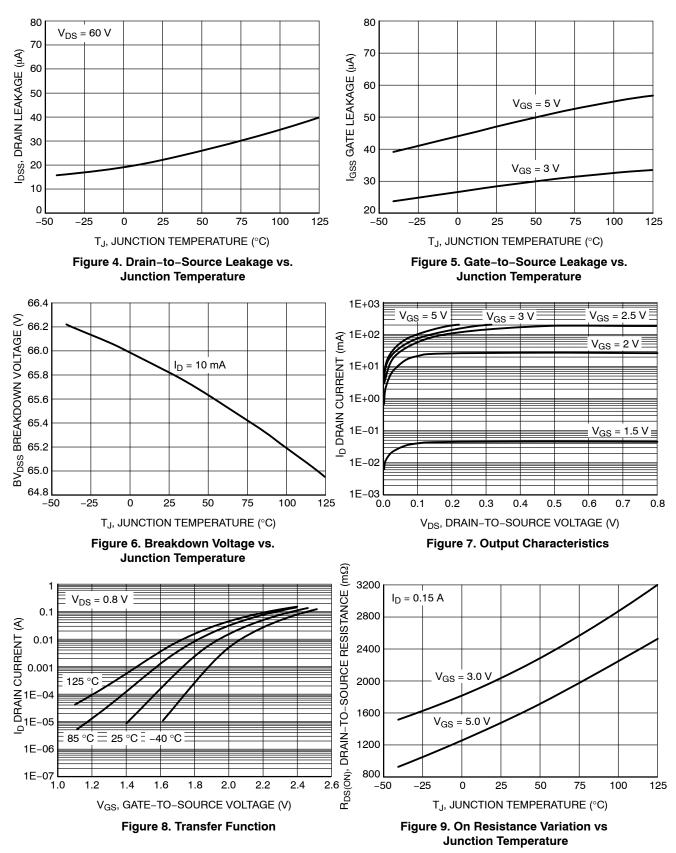


Figure 3. Load Dump Waveform Definition

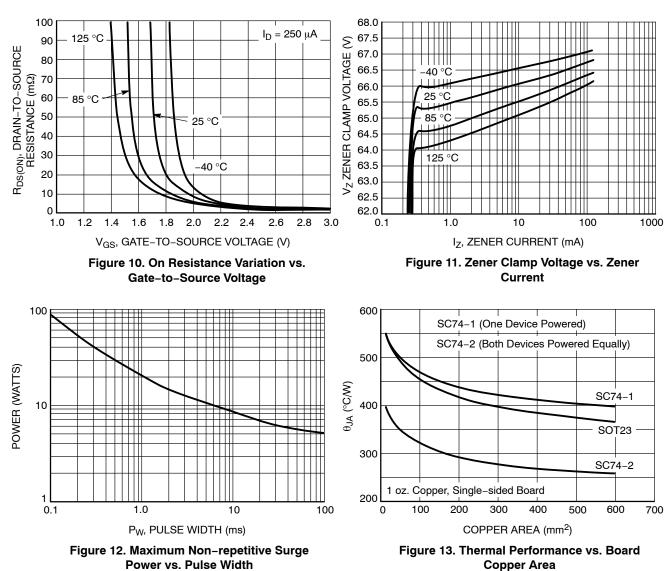
TYPICAL PERFORMANCE CURVES

 $(T_J = 25^{\circ}C \text{ unless otherwise specified})$



TYPICAL PERFORMANCE CURVES

 $(T_J = 25^{\circ}C \text{ unless otherwise specified})$



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APPLICATIONS INFORMATION

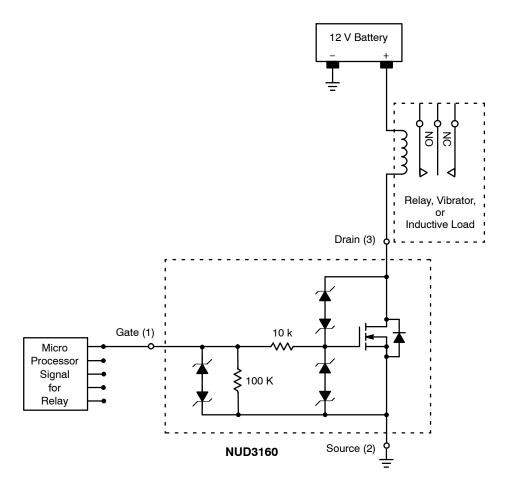


Figure 14. Applications Diagram

semi



SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318**

ISSUE AU

DATE 14 AUG 2024













XXX = Specific Device Code М = Date Code

= Pb-Free Package .

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MILLIMETERS					
DIM	MIN	NOM	МАХ		
А	0.89	1.00	1.11		
A1	0.01	0.06	0.10		
b	0.37	0.44	0.50		
с	0.08	0.14	0.20		
D	2.80	2.90	3.04		
E	1.20	1.30	1.40		
е	1.78	1.90	2.04		
L	0.30	0.43	0.55		
L1	0.35	0.54	0.69		
Ηe	2.10	2.40	2.64		
Т	0°		10°		

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2. MILLIMETERS.

MILLIME IERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE 3.

BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS, OR GATE BURRS.

RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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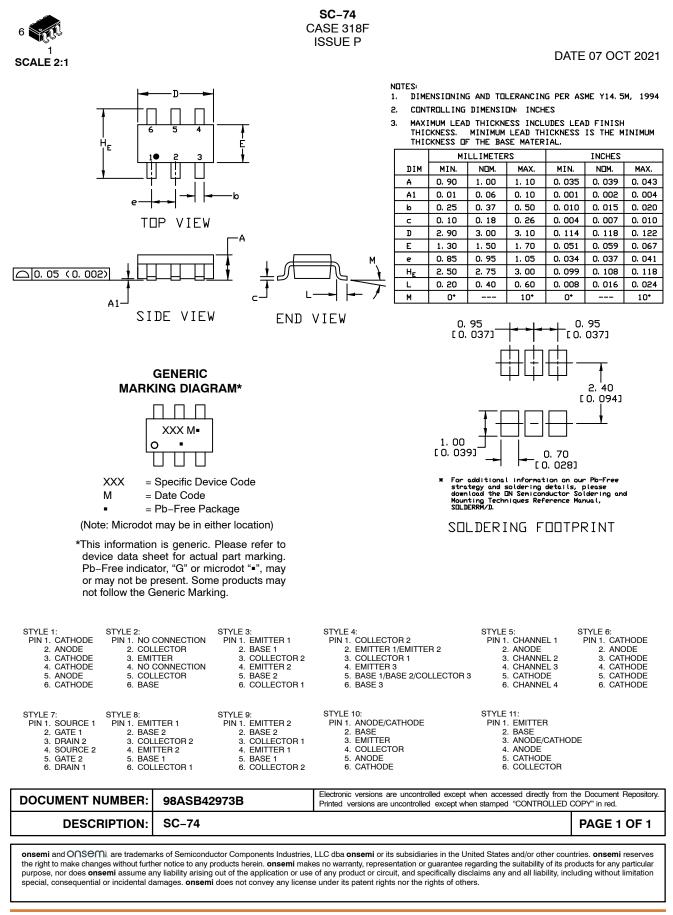
DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	I	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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